

# SIMBOL-X High Energy Detector CdTe / CdZnTe developments in Saclay

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# Summary ...

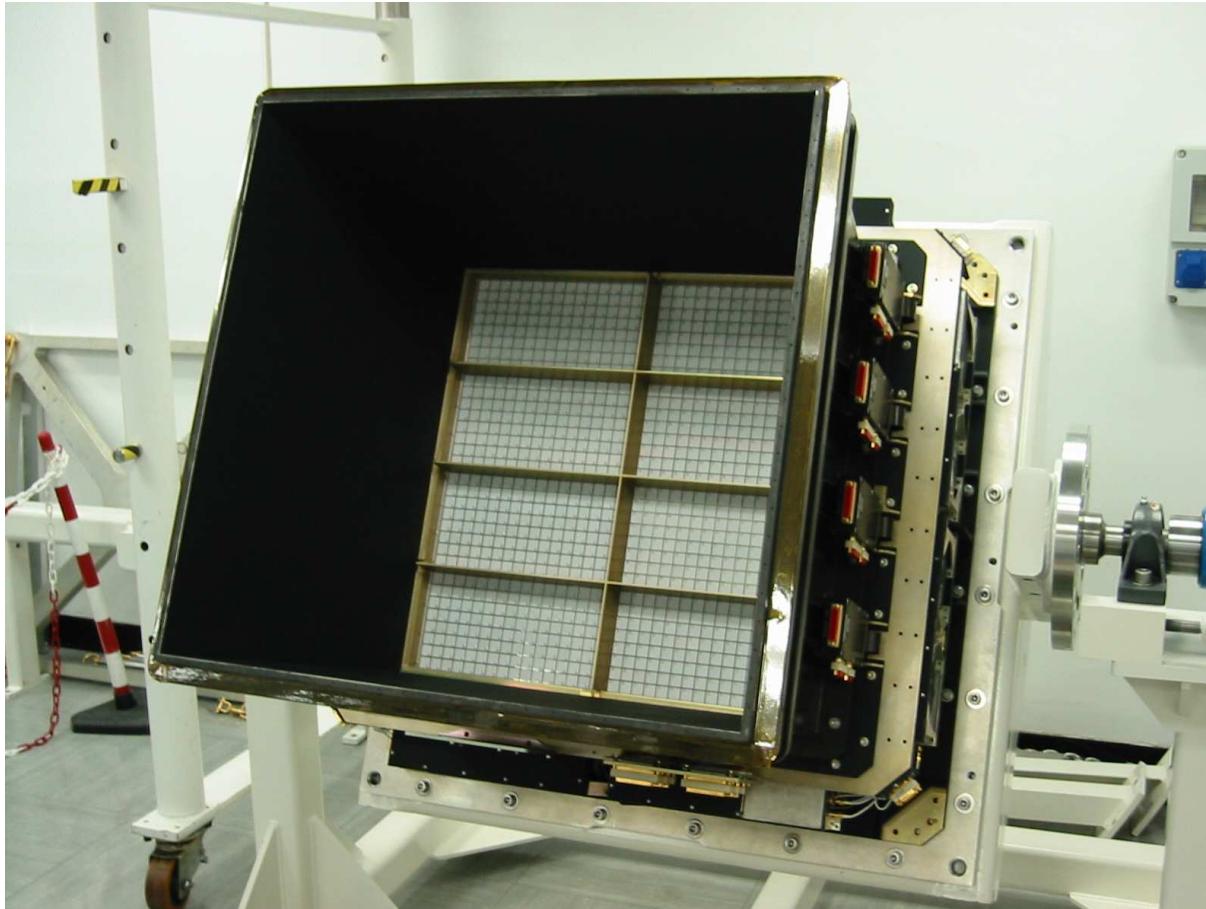


- CdTe / CdZnTe R&D program in Saclay
- SIMBOL-X High energy detector concept
- A few preliminary results on detectors
- A few preliminary results on IDef-X ASIC
- Snap-shot on the development plan

## Motivations ... first of all

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- Successful launch of *INTEGRAL* satellite with *ISGRI CdTe Imager* on board



# Motivations ...

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- Increasing demands for new semiconductor detectors for X and  $\gamma$ -rays (**medical, space, nuclear and physics applications**)
- Recent progress in technology of producing Cd(Zn)Te (**stability and reproducibility**)
- New techniques to improve simultaneously spatial and energy resolution of CdTe
- Development of integrated front-end electronics technologies (**ASIC**)
- Hybridization techniques in huge development (**ASIC + detectors**)

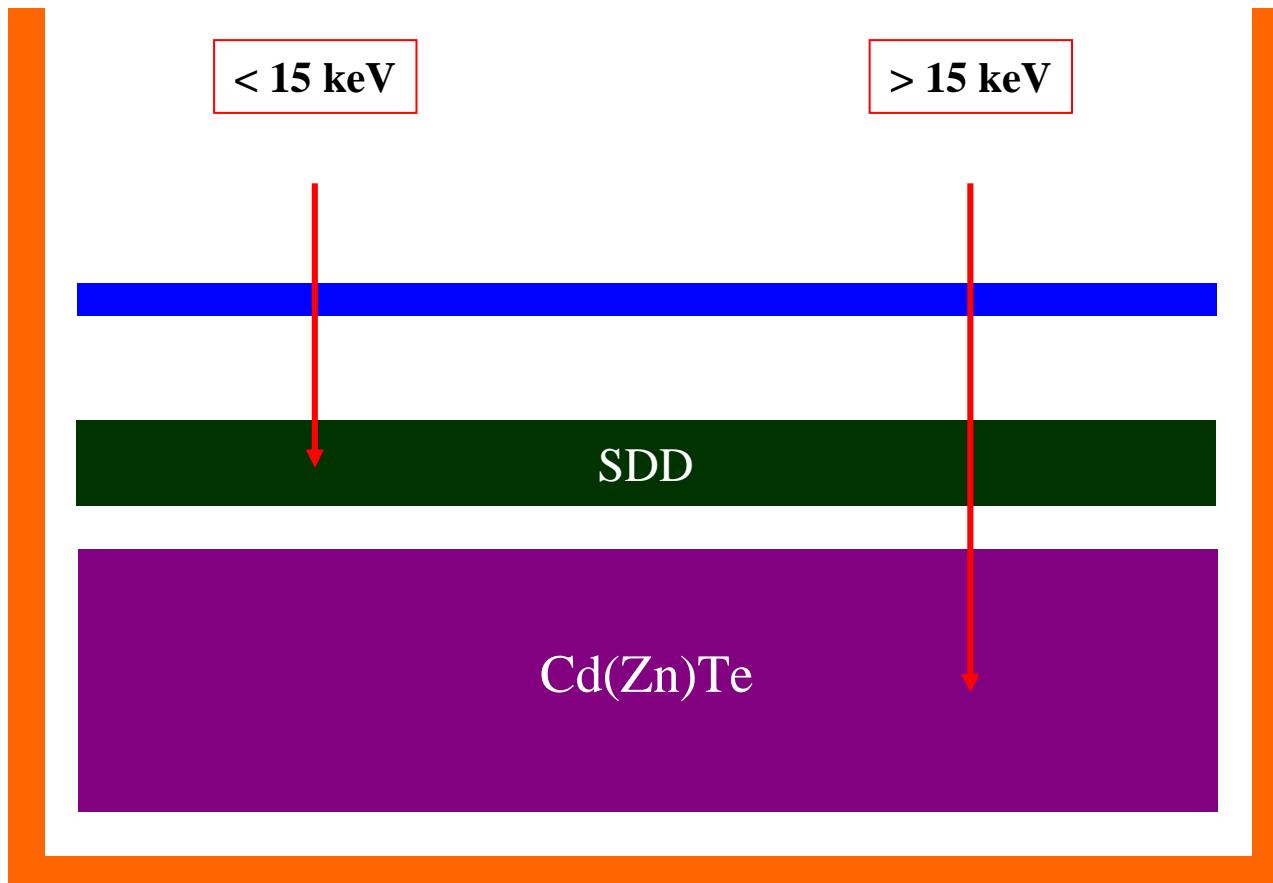
# Motivations ...



- New generation of hard X-Ray telescopes will be based on focusing designs
- We want to further develop CdTe for such telescopes focal planes
- Because CdTe offers :
  - Room temperature operations
  - High spatial resolution
  - High energy resolution
  - High detection efficiency
  - Good timing resolution

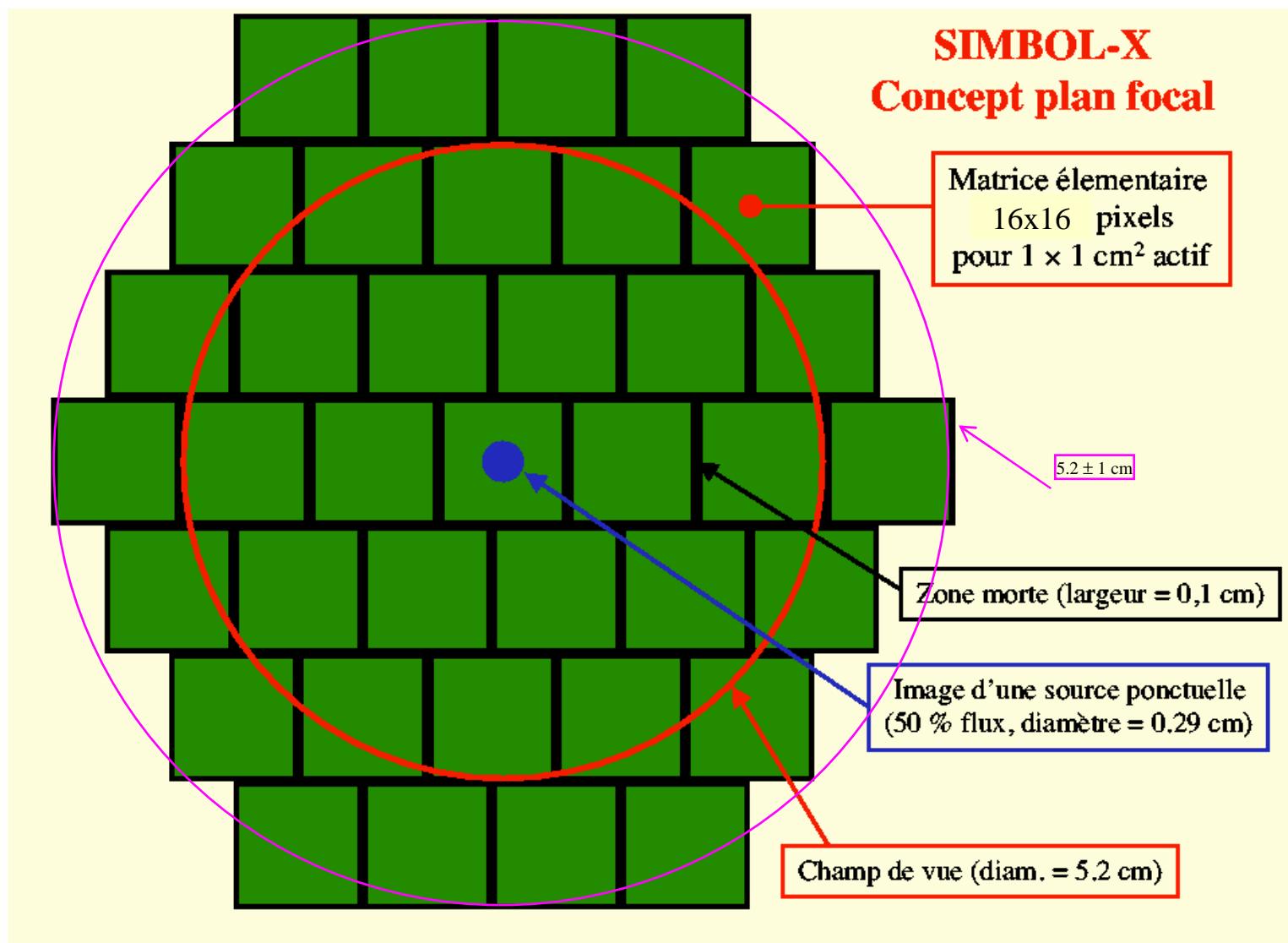
# Symbol-X detector unit concept ...

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# SIMBOL-X CZT detector unit ...

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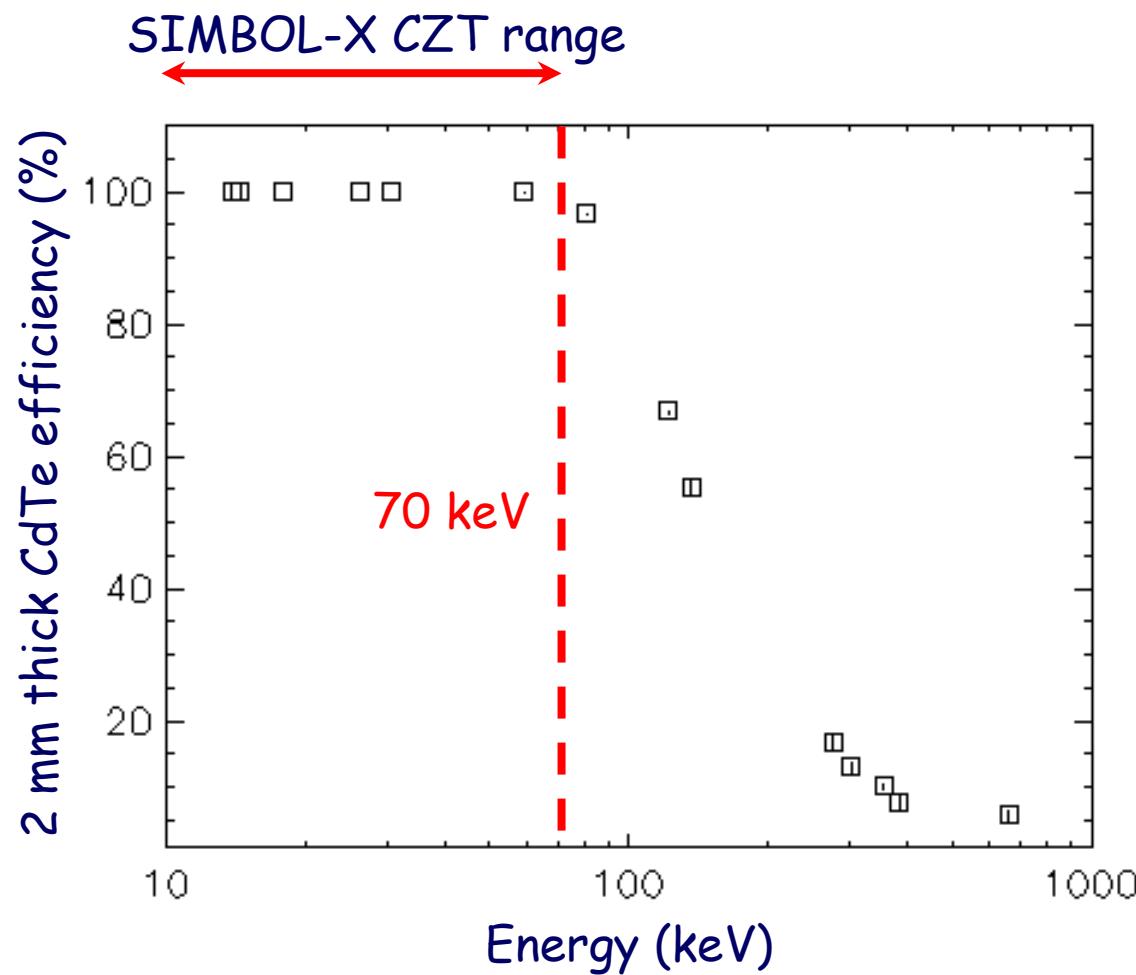
## Spatial resolution ...



- SIMBOL-X PSF needs  $750 \times 750 \mu\text{m}^2$  pixel size (max. size)
- 1 cm<sup>2</sup> detectors available on the market of CdTe and CdZnTe today
- The spatial resolution doesn't seem to be challenging regarding current technology
- Limitations will come from ASIC circuit design and hybridization capabilities

# CdTe detection efficiency ...

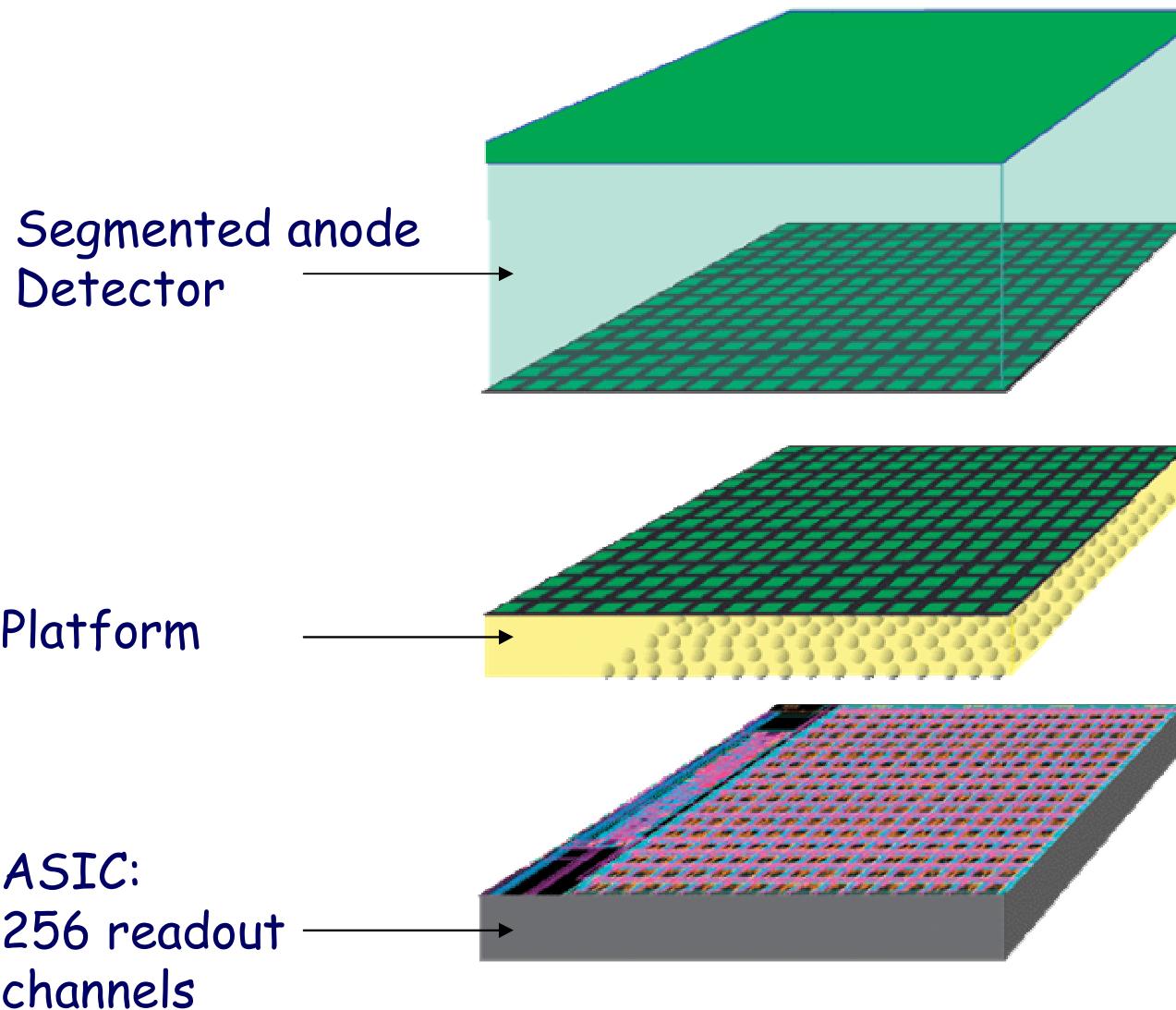
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- CdTe is 100% efficient in the SIMBOL-X energy range for 2 mm thickness

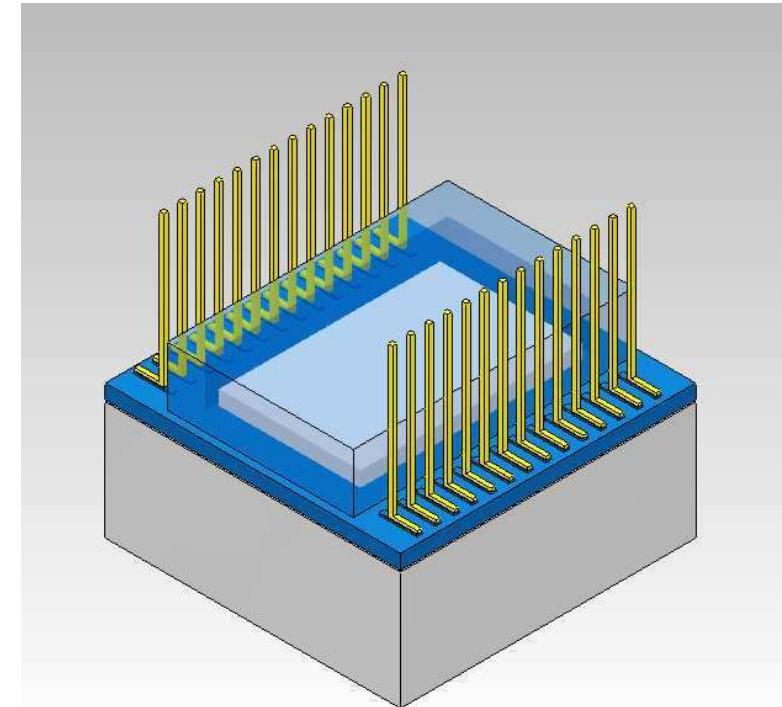
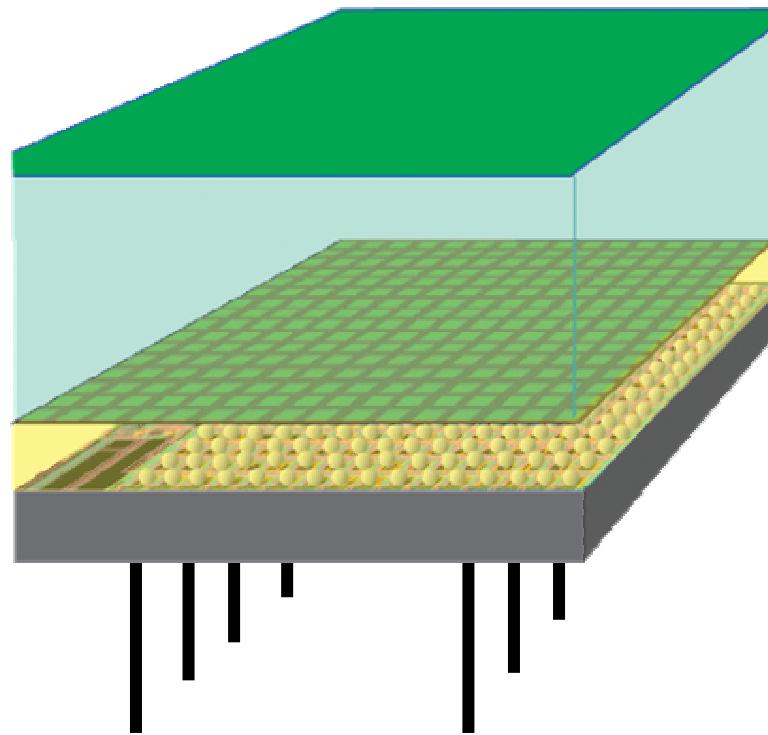
# 256 pixels CZT system ...

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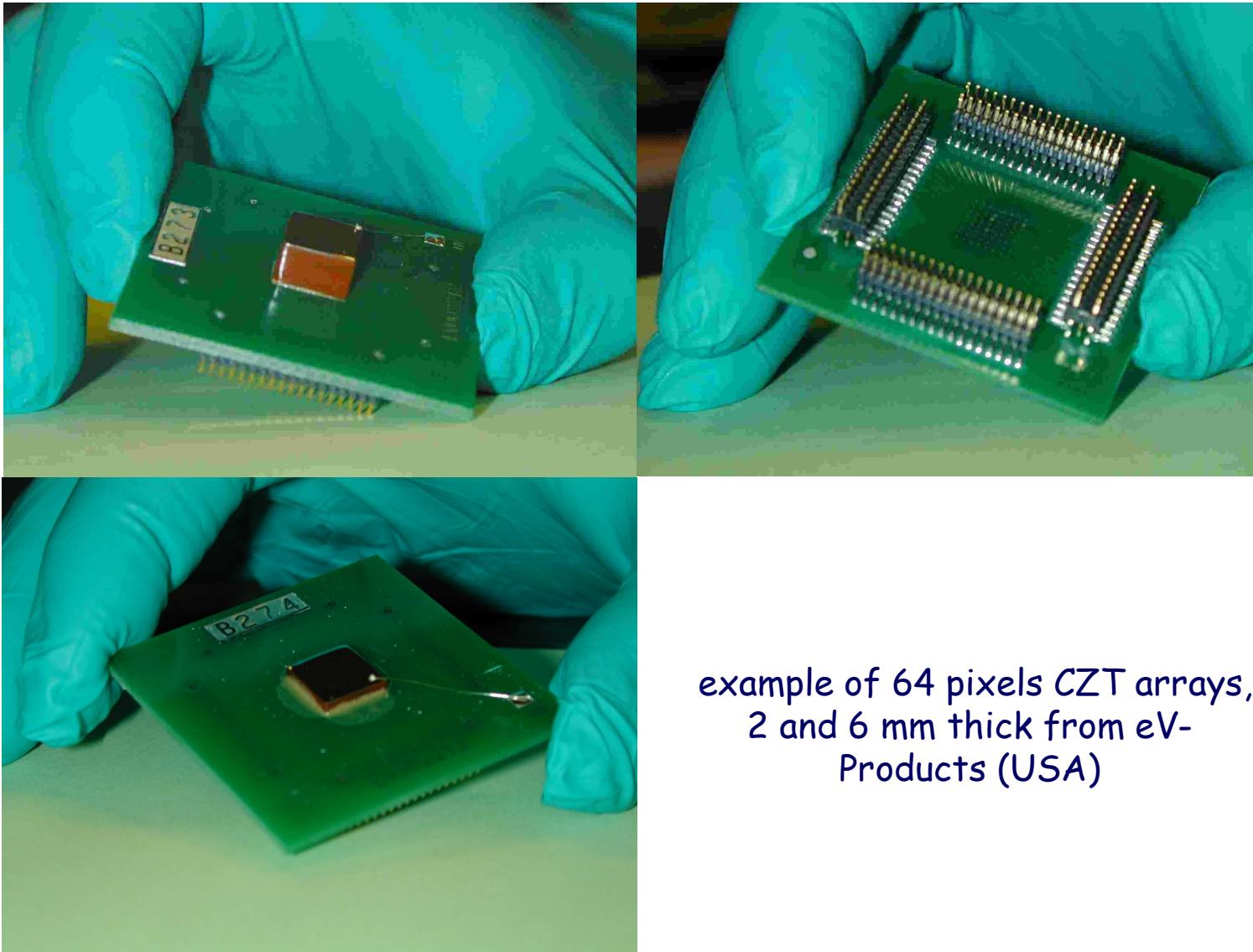
# 256 pixels CZT system ...

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# CZT detectors arrays in Saclay ...

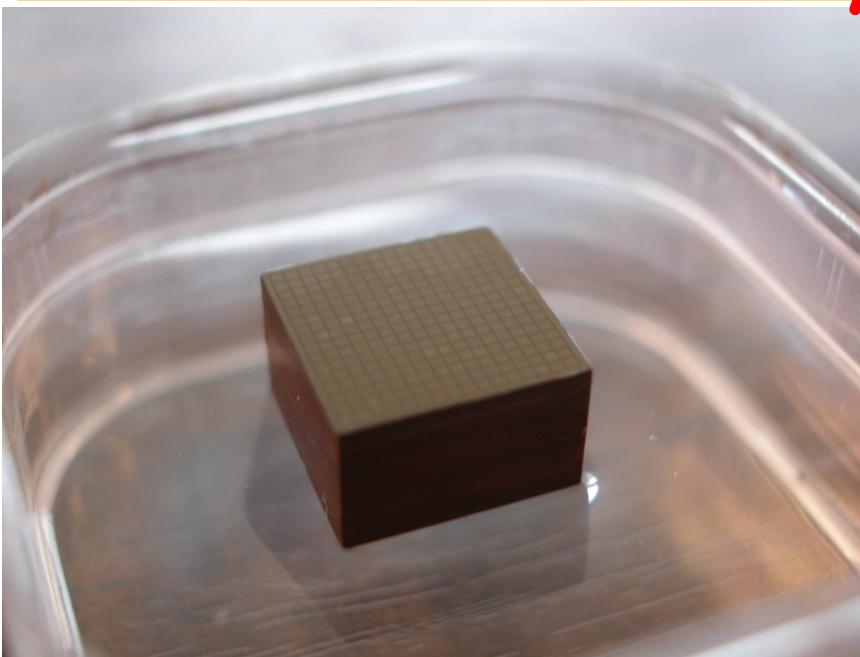
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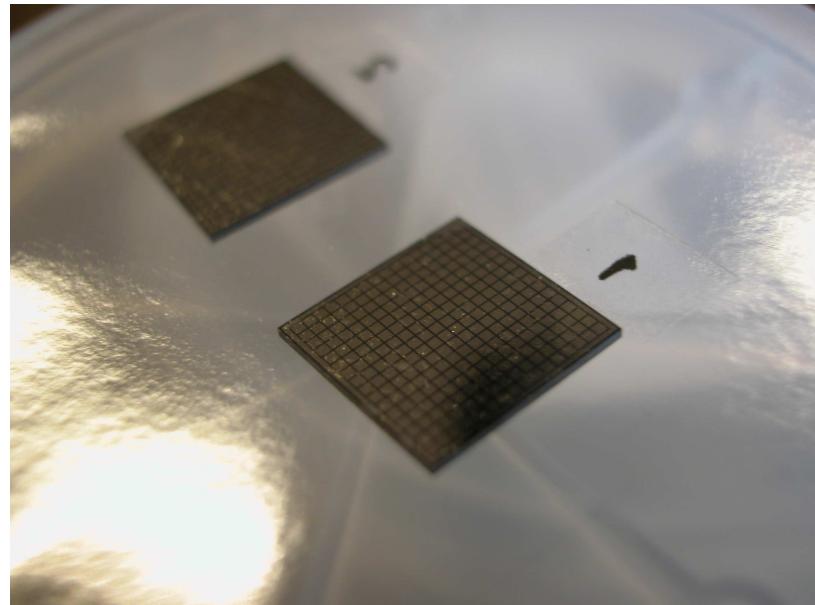
example of 64 pixels CZT arrays,  
2 and 6 mm thick from eV-  
Products (USA)

# CZT detectors arrays in Saclay ...

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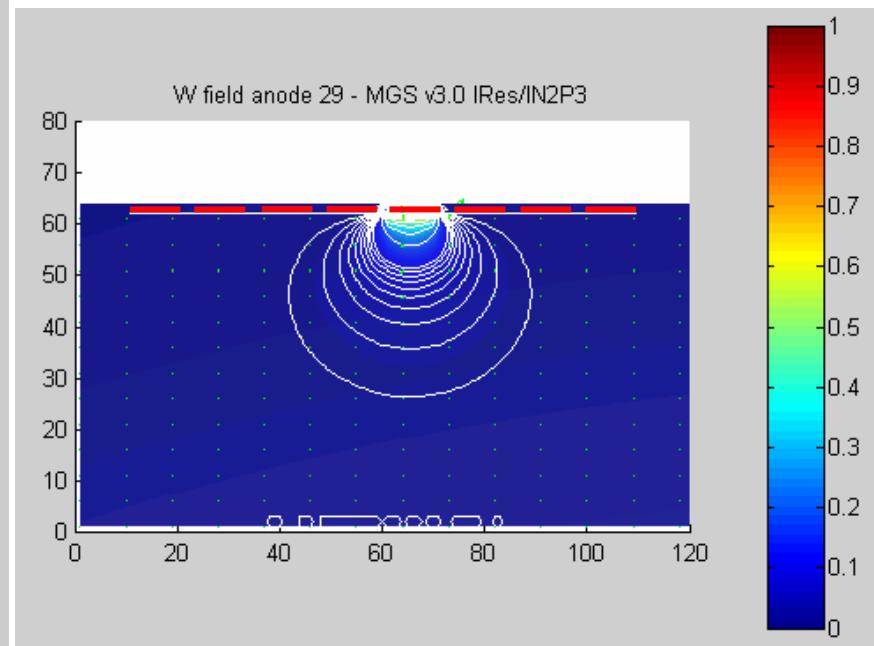
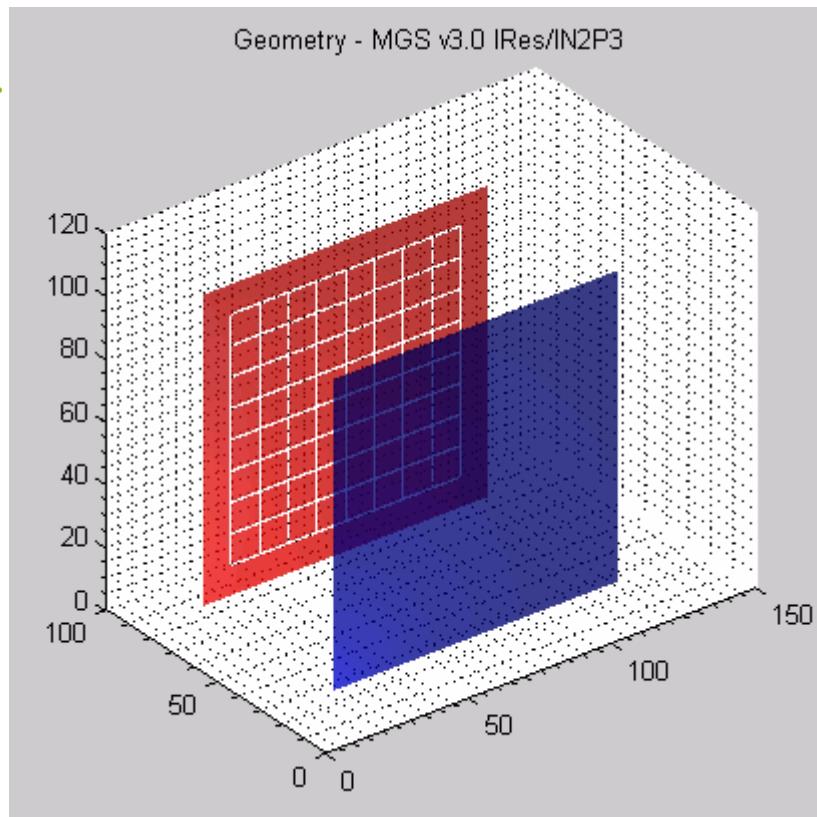
example of 256 pixels CZT arrays,  
6 mm thick from eV-Products  
(USA)



example of 256 pixels Schottky  
arrays, 0.5 mm thick from  
ACRORAD (Japan)

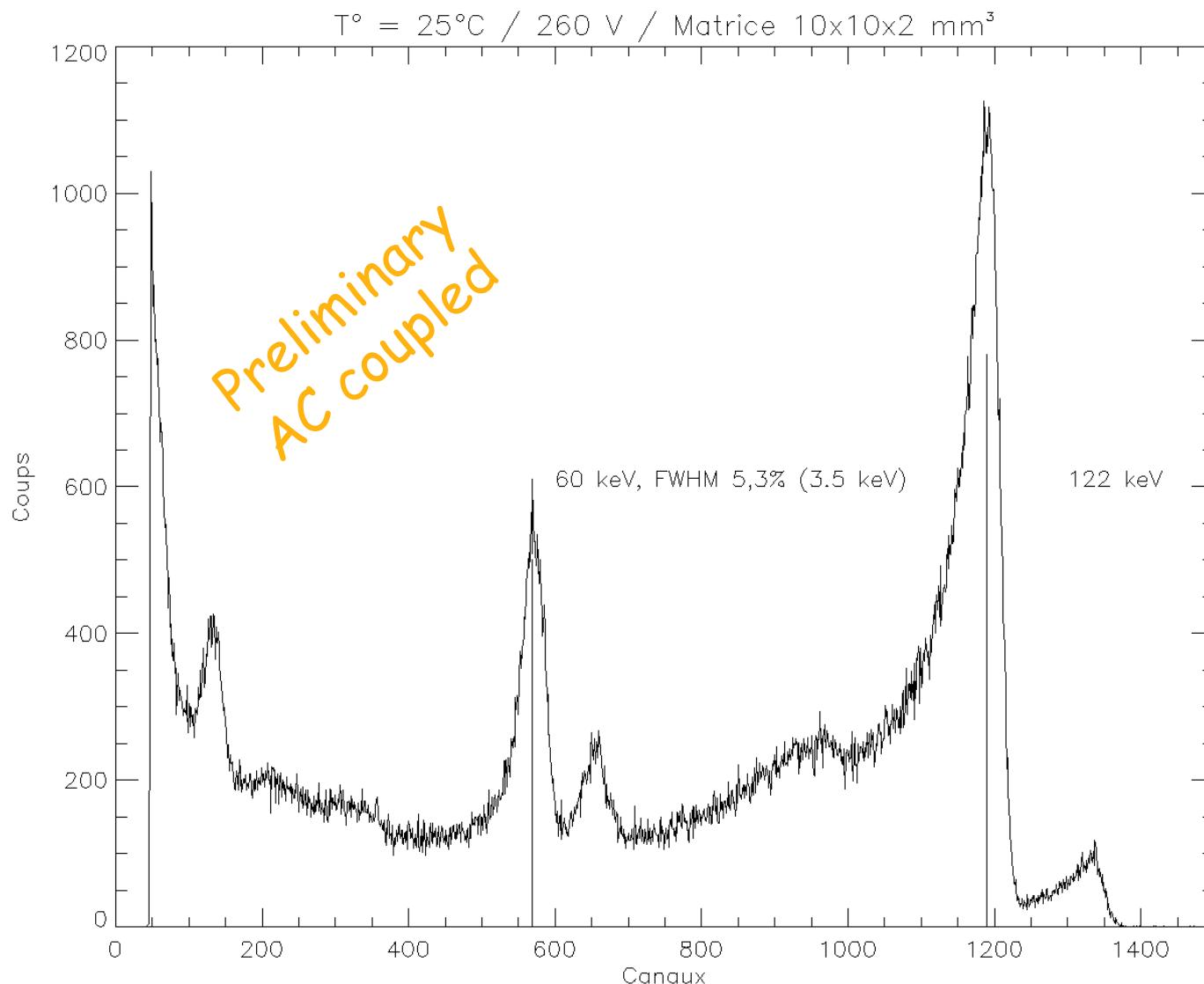
# 3D modeling, Weighting field ...

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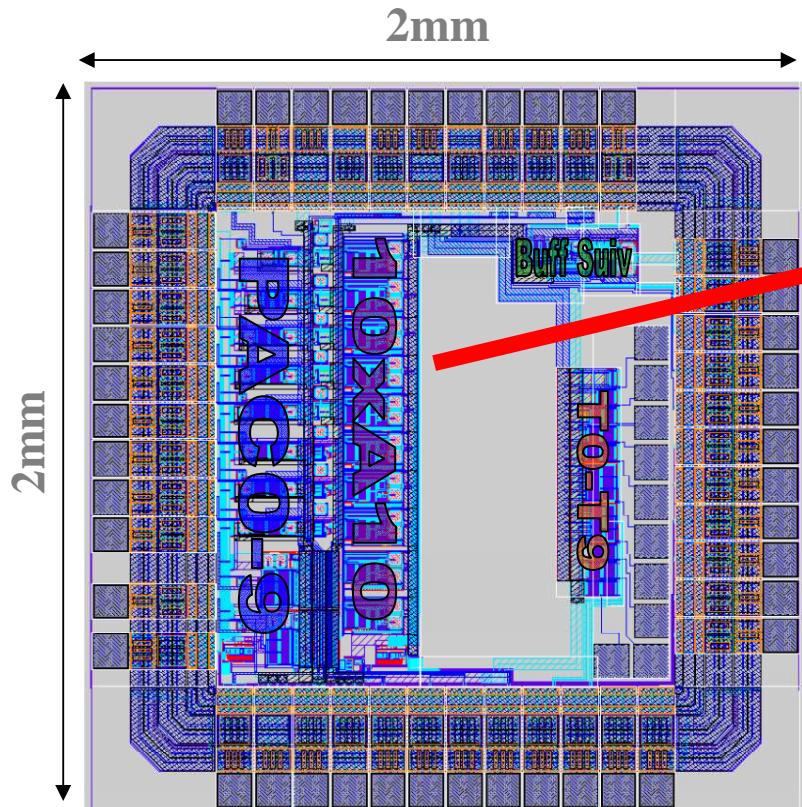
# Low energy response, 2mm ...

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# IDeF-X V0, first circuit ...

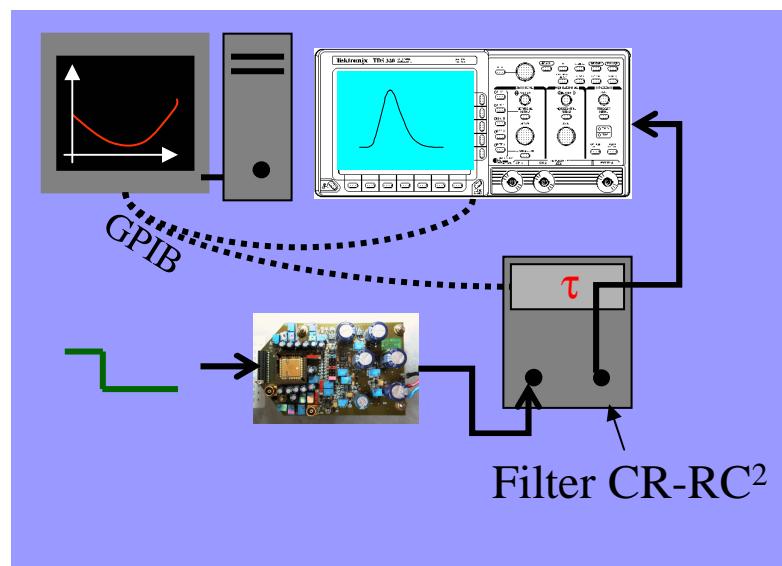
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**IDeF-X V0 Circuit : layout**



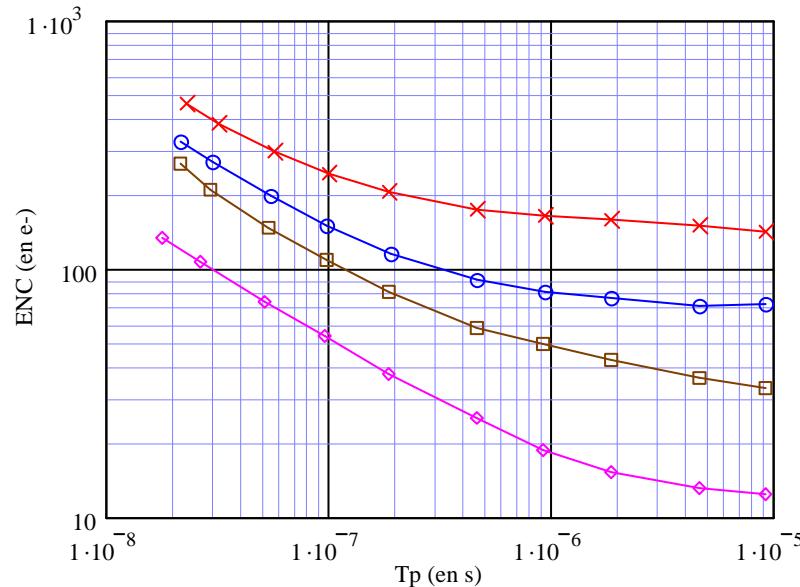
**Test board**



# Results ...

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Charge sensitive preamp:



Configuration

ENC (e- rms)

Pad+Bonding+PCB

140

Pad+Bonding

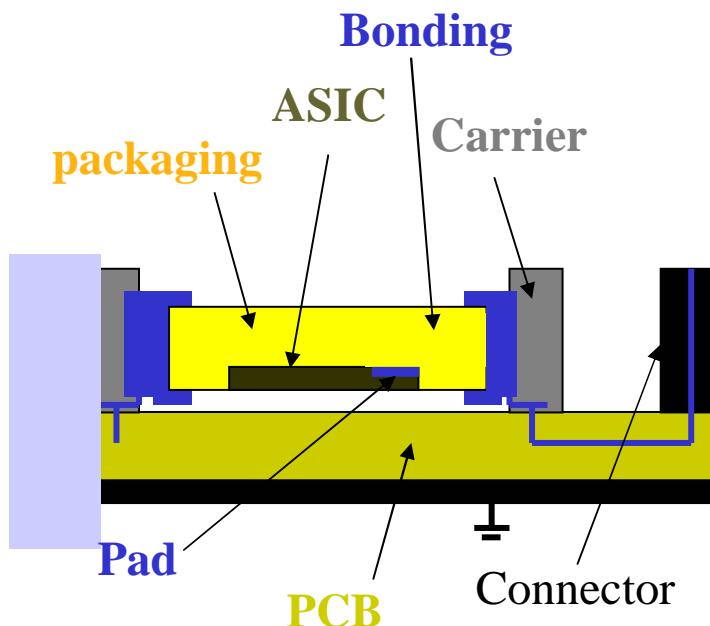
71

Pad

33

Without pad

12



Corresponding energy resolution  
CdZnTe (FWHM eV)

1454

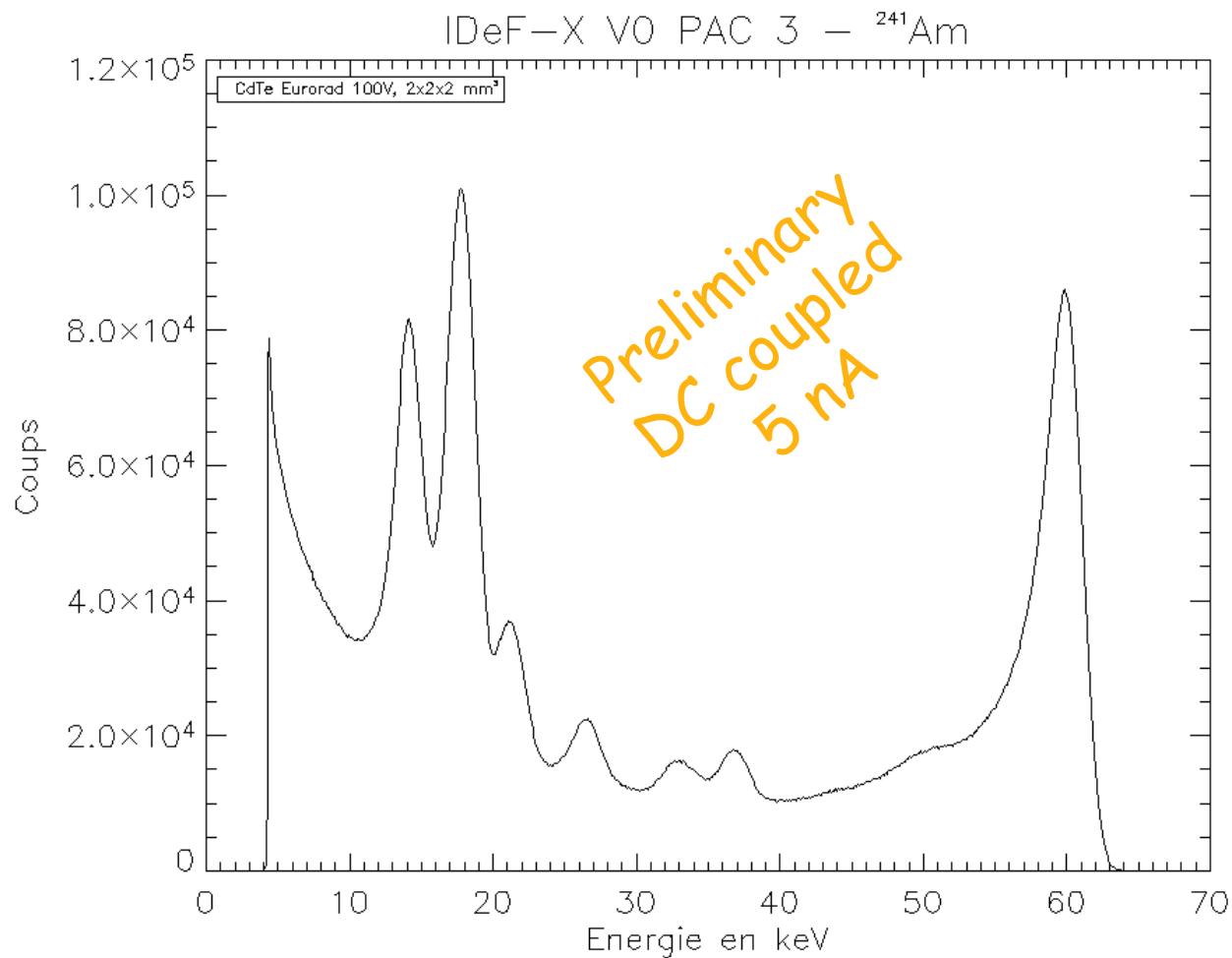
737

342

125

# Low energy response, 2mm CdTe ...

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- Next step : low current detectors, 1 to 1.5 keV FWHM resolution expected at 60 keV

# CZT detectors development plan ...



- Three main steps until 2005-2006
- 2003 : Demo detector, first run of ASIC (CSA cf. Francis Lugiez), mechanical set up
- 2004 : Choice for the geometry, study of the hybridization process, IDef-X V1.1 and V1.2, study of the digital part
- 2005-2006: Final design, realization of a complete prototype (256 channels)